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<b>INFORMATION DISCLOSURE CITATION BY APPLICANT</b> <i>(USE SEVERAL SHEETS IF NECESSARY)</i>				<b>APPLICANT:</b> <b>Fabrice Pardo et al.</b>	
				<b>FILING DATE:</b> <b>January 21, 2005</b>	<b>GROUP ART UNIT:</b>

  

U.S. PATENT DOCUMENTS							
Examiner Initial		Document No.	Date	Name	Class	Subclass	Filing Date if Appropriate
	A	5,227,648	07/1993	Woo			
	B	5,663,639	09/1997	Brown et al.			
	C						
	D						
	E						

  

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	F	0 651 448 A1	03/1995	European			Corresponds to U.S. Patent No.: 5,512,763
	G	2 803 950	07/2001	France			Corresponds to U.S. Publication No.: 2003/010979
	H						

  

OTHER REFERENCES <i>(Including Author, Title, Date, Pertinent Pages, Etc.)</i>	
I	Katsumi Kishino et al., "Resonant Cavity-Enhanced (RCE) Photodetectors, August 8, 2001, pages 2025 - 2034,
J	Wolfgang Kowalsky et al., "High Bandwidth Metal-Semiconductor-Metal Photodiodes with Integrated Fabry-Perot Resonator for WDM Receivers", August 1992, Pages 214 - 216
K	A. Strittmatter et al., "High-Speed, High Efficiency Resonant-Cavity Enhanced InGaAs MSM Photodetectors", Pages 1231- 1232 <b>20 June 1996</b>
L	A. Strittmatter et al., "High-Frequency , Long-Wavelength Resonant-Cavity-Enhanced InGaAs MSM Photodetectors", September 15, 1996, Pages 145 - 148
<b>Examiner:</b> <span style="float: right;">/John Ingham/</span>	
<b>Date Considered</b> <span style="float: right;">08/14/2009</span>	
<b>*Examiner:</b> Initial if reference considered, regardless of whether citation is in conformance with MPEP 609; Draw line through citation if not in conformance <u>and</u> not considered. Include copy of this form with next communication to applicant.	